

L Number	Hits	Search Text	DB	Time stamp
1	318	(372/68).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:16
2	467	(385/45).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:16
3	420	(372/66).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:16
4	911	(385/17).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:16
5	1978	(372/50).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:16
6	518	(385/46).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:16
7	539	(372/97).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:16
8	251	(372/\$.ccls. 385/\$.ccls.) and ((multi adj mode multimode) adj2 interference MMI) adj (region coupler) and (wave adj guide waveguide)	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:17
9	156	laser and semiconductor and (active emission) adj layer and (waveguid\$3 (wave adj guid\$3)) and interference and electrode and (monolithic mono adj lithic)	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:17
10	616	(385/28).CCLS.	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:17
11	323	((385/28).CCLS.) and laser	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:17
12	64	((385/17).CCLS.) and semiconductor adj laser	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:18
13	72	((385/28).CCLS.) and semiconductor adj laser	USPAT; US-PPGPUB; EPO; JPO; DERWENT	2004/08/20 11:18